PAN	ĴΤ
	SEMI CONDUCTOR

### 60V N-Channel Enhancement Mode MOSFET

Current

10 A

### Features

Voltage

• RDS(ON), VGS@10V, ID@10A<12mΩ

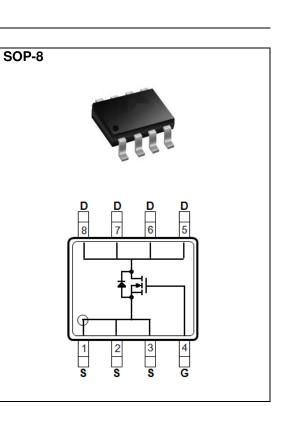
60 V

- RDS(ON) , VGS@4.5V, ID@5.0A<15mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.

(Halogen Free)

### **Mechanical Data**

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9434A



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current	T <sub>A</sub> =25°C		10	
	T <sub>A</sub> =70°C	I <sub>D</sub>	8	A
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	40	А
Power Dissipation	T <sub>A</sub> =25°C	_	2.5	
	T <sub>A</sub> =70°C	P <sub>D</sub>	1.6	W
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	5.0	mJ
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance - Junction to Ambient, t $\leq$ 10s (Note 6)		R <sub>eJA</sub>	50	°C/W



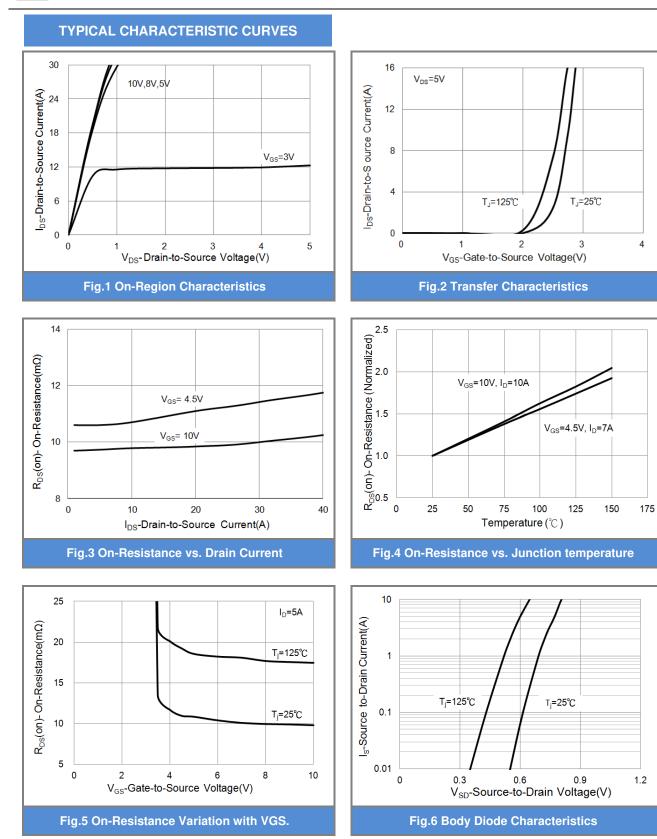
## **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

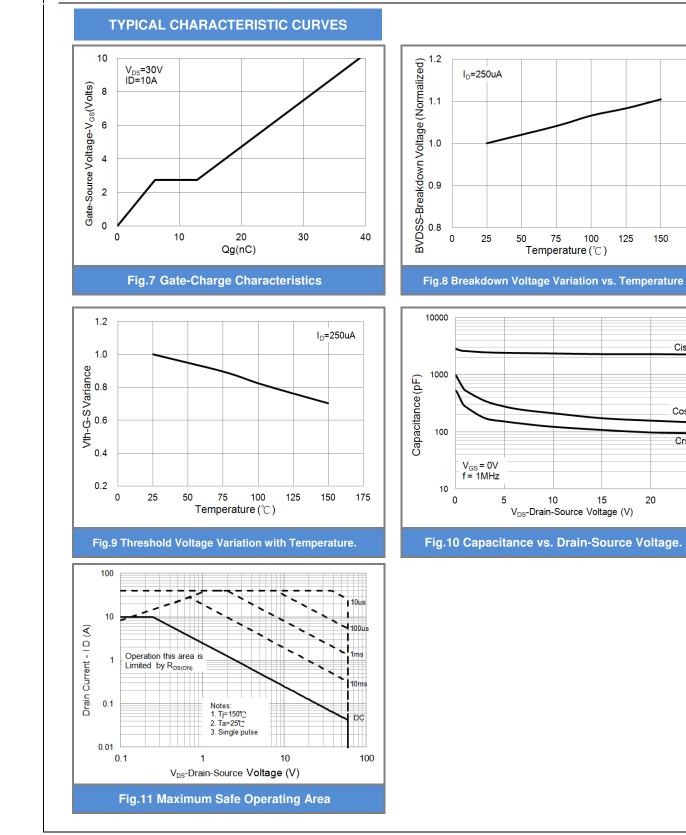
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V,I_{D}=250uA$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.7	2.5	V
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{GS}$ =10V, $I_{D}$ =10A	-	10.5	12	mΩ
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{GS}$ =4.5V,I <sub>D</sub> =5A	-	12	15	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =60V, $V_{GS}$ =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	$V_{DS}=30V, I_{D}=10A, V_{GS}=10V$ (Note 1,2)	-	39	-	
Gate-Source Charge	$Q_{gs}$		-	6.1	-	nC
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =10V	-	6.7	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	2256	-	pF
Output Capacitance	Coss		-	145	-	
Reverse Transfer Capacitance	Crss		-	93	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}=15V, I_{D}=10A,$ $V_{GS}=10V, R_{G}=6\Omega$ (Note 1.2)	-	7.5	-	-
Turn-On Rise Time	tr		-	36	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	49	-	
Turn-Off Fall Time	tf		-	12	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			_	- 10	10	А
Diode Forward Current	I <sub>S</sub>		-		10	
Diode Forward Voltage	$V_{\text{SD}}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.67	1.0	v

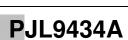
NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH,  $I_{AS}{=}10A,\,V_{DD}{=}50V,\,V_{GS}{=}10V$
- 6. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.













125

150

175

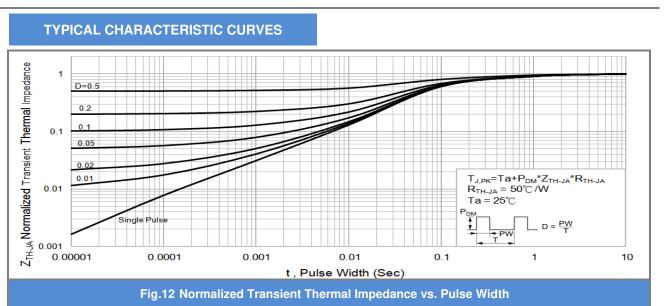
Ciss

Coss

Crss

25

20



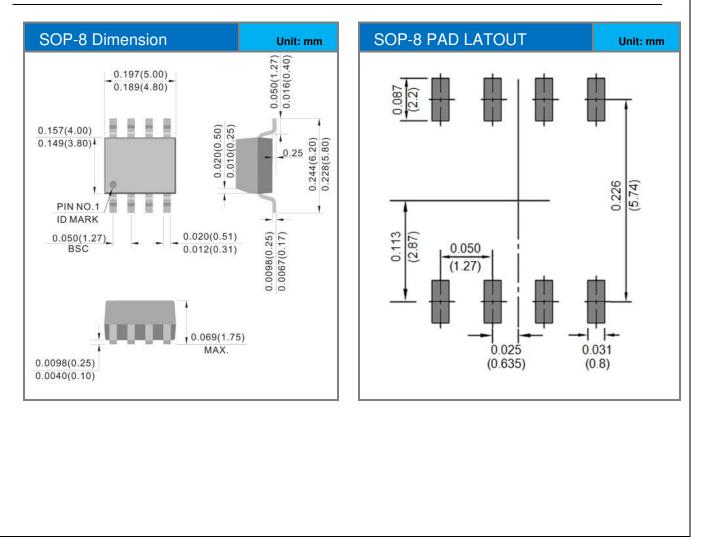




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9434A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9434A	Halogen free

### Packaging Information & Mounting Pad Layout





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